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HITT GAINES & BOISBRUN

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"Reply under 37 CFR 1.116
--Expedited Procedure--
Examining Group 2811

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ATTORNEY DOCKET NO.: LOTFI 22-2

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Ashraf W. Lotfi, *et al.*

Serial No.: 09/448,856

Filed: November 23, 1999

Title: SiC NMOSFET FOR USE AS A POWER SWITCH AND
A METHOD OF MANUFACTURING THE SAME

Group: 2811

Examiner: Ori Nadav

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TECHNOLOGY CENTER 2800

Commissioner for Patents
Washington, D.C. 20231

Sir:

I hereby certify that this correspondence is being facsimile
transmitted to the Patent and Trademark Office (Fax No. (703)
872-9319) on 12/10/2002

EDITH SHEK

Typed or printed name of person signing this certificate

Edith Shek

Signature

AMENDMENT UNDER 37 C.F.R. § 1.116

In response to the Examiner's Action mailed October 11, 2002, please amend the above-
identified application as follows:

IN THE CLAIMS:

(1) Please amend Claim 44 as follows:

44. (Amended) A semiconductor device, comprising: